

Highly Spin-Polarized Field Emissions Induced by Quantum Size Effects in Ultrathin Films of Fe on W(001)

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Spin-polarized field emissions from Fe pseudomorphic ultrathin films on W(001) surfaces are studied by density functional calculations. We found that nearly completely spin-polarized field emission currents can be realized in two and four Fe layers on W(001) and that these systems have the additional advantages of thermal stability and low work functions. The unusually high spin polarizations of the field emission current is traced to the Fe film's quantum size effects leading to spin-polarized quantum well states and surface resonance states.

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Nanostructured systems have enhanced effects due to the confinement of quantized states, and, for the particular case of ultrathin supported films, many amazing structural and electronic properties have been discovered [1]. We will see that such confinement effects can give interesting and potentially useful phenomena in spin-polarized field emission (FE). Although tungsten is the metal of choice for emitter tips, it does not produce spin-polarized FE currents. We propose adding a thin coating of ferromagnetic material to tungsten to generate highly spin-polarized FE. Because the FE electrons tunneling out of a ferromagnetic material surface are usually not strongly polarized [2–5], this is not a simple proposition as we must consider factors like the work function change, thermal stability, and most importantly, the strength of the polarization of electrons tunneling out of the magnetic layer. In our analysis of the quantum size effects of spin-polarized FE, we found that there exist configurations of Fe/W(001) under which all the aforementioned conditions are favorable.

Fe/W systems have been investigated by many researchers. Chrobok *et al.* measured spin-polarized FE currents from different Fe films on W tips and massive Fe tips [4]. They did not report on the structural characterization of the films. Other experiments found that Fe grows pseudomorphically on W(001) surfaces in the first few monolayers (ML) [6–9]. In particular, the first two ML form wetting layers that are stable upon annealing up to 700 K [6]. A recent spin-resolved scanning tunneling microscopy experiment [10] investigated the electronic structure of Fe pseudomorphic films on W(001) surfaces with two to four layers of coverage.

In this Letter, we use density functional calculations to study the spin-polarized FE from pseudomorphic Fe ultrathin films on W(001). Our results show that the electron spin polarization (ESP) of the FE current depends strongly on the thickness of the Fe layers. In particular, nearly complete spin polarization can be realized in two and four ML of Fe/W(001). These configurations have the

additional advantages of energy stability and low work functions.

Our formulation for the FE current is based on the local-density approximation (LDA), which has been described elsewhere [11]. The FE current density contributed by a state labeled as $(\sigma, n, \vec{k}_{\parallel})$ (spin, band, and k point indices) of the emitter under an external electric field (E -field), F , can be written as

$$J_{\sigma, n, \vec{k}_{\parallel}} = \sum_{\vec{G}_{\parallel}} |f_{\sigma, n}(\vec{k}_{\parallel} + \vec{G}_{\parallel}, z_m)|^2 g(\varepsilon_{\sigma, n, \vec{k}_{\parallel}}, \vec{k}_{\parallel} + \vec{G}_{\parallel}, z_m), \quad (1)$$

where $f_{\sigma, n}(\vec{k}_{\parallel} + \vec{G}_{\parallel}, z)$ is the plane-wave expansion coefficient of the eigenstate wave function in a slab geometry, $g(\varepsilon_{\sigma, n, \vec{k}_{\parallel}}, \vec{k}_{\parallel} + \vec{G}_{\parallel}, z_m) = \frac{\hbar}{\pi m} (\frac{2mEF}{\hbar^2})^{1/3} |\text{Bi}[(\frac{2mEF}{\hbar^2})^{1/3} \times (z_a - z_m)]|^{-2}$ is interpreted as a tunneling factor related to the Airy function, Bi, $\varepsilon_{\sigma, n, \vec{k}_{\parallel}}$ is the eigenenergy, and z_a is the classical turning point for the linear potential in the vacuum region. There is a range of matching point values z_m (see [11]) that can be used, and we use $z_m = 8 \text{ \AA}$ away from the Fe film surface. The total energy distribution (TED) of the FE current density with spin σ can be written as $J_{\sigma}(E) = \sum_{n, \vec{k}_{\parallel}} \delta(E - \varepsilon_{\sigma, n, \vec{k}_{\parallel}}) \eta(\varepsilon_{\sigma, n, \vec{k}_{\parallel}}) J_{\sigma, n, \vec{k}_{\parallel}}$, where $\delta(E)$ and $\eta(\varepsilon_{\sigma, n, \vec{k}_{\parallel}})$ means the δ -function and Fermi-Dirac occupation function (T is set at 78 K) respectively [12]. The ESP value is obtained from $P = (J_{\text{total}, \uparrow} - J_{\text{total}, \downarrow}) / (J_{\text{total}, \uparrow} + J_{\text{total}, \downarrow})$, where $J_{\text{total}, \sigma} = \int J_{\sigma}(E) dE$.

The electronic structure of the emitter under an external E -field is determined using the projected augmented wave (PAW) method [13–16] and the Perdew-Burke-Ernzerhof (PBE) form [17] of the generalized gradient approximation (GGA) with a plane-wave cutoff of 335 eV. We used a slab geometry consisting of 11 (or more, for convergence tests) layers of W and up to five epitaxial layers of Fe. In agreement with previous calculations [18,19], we found that the ground state for one ML Fe/W(001) is antiferromagnetic, and thus our spin-polarized FE calculations are

done for two to five Fe layers, which have ferromagnetic ground states. The external E -field is applied in the (001) direction. The supercell has a vacuum thickness of 25 Å. All atoms are fully relaxed.

Figure 1, panels (a1)–(a4) show our calculated TED curves of the FE currents from the Fe films on W(001) surface under an E -field of 0.2 V/Å. The most important observation is that the ESP values are close to -100% (i.e. FE current is nearly entirely minority-spin) for two and four ML. When we examine the calculated local density of states (LDOS), we found that the Fe surface layer is dominated by the minority-spin LDOS near the Fermi level (E_F). While the dominance of minority-spin LDOS near E_F is expected and is consistent with the negative ESP from two to four layers, it cannot explain the nearly -100% ESP at two and four layers, nor can it explain the positive ESP at five ML of Fe. This observation highlights the importance of the details of the band structure and the wave function characteristics of the emitter.

The dominance of the minority-spin current at two ML is due to quantum well (QW) states, and to see how that happens, we have to examine the details. Previous studies showed that the FE current is dominated by contributions from the states near the E_F and $\bar{\Gamma}$, and that states with s , p_z and d_z^2 components contribute more FE current than other states. Consequently, we examine the QW state in the Fe film with Δ_1 symmetry at $\bar{\Gamma}$. Figure 2(a) shows the band

structure of a W bcc bulk crystal and Figs. 2(b) and 2(d) show the spin-polarized band structure of an Fe body-centered tetragonal (bct) bulk crystal (with the same in-plane lattice constant as bcc W and the z -coordinates relaxed) along the ΓH line. Figs. 2(c) and 2(e) are, respectively, the calculated QW states at $\bar{\Gamma}$ with Δ_1 symmetry for the majority and minority spins localized in the Fe film. By comparing Figs. 2(a) and 2(b), we see that there is a wide Δ_1 symmetry gap in W along the (001) direction that allows for the localization of Fe majority-spin QW states, and, indeed, we see from Fig. 2(c) that some majority-spin QW states localized in the Fe film with Δ_1 symmetry (at $\bar{\Gamma}$) are formed between -2 eV and $+2$ eV relative to the E_F . For the two and four ML Fe films, all occupied majority-spin QW states are far below E_F . They therefore have little effect on the ESP of the FE current. For the three and five ML Fe film, there are majority-spin QW states with the number of nodes (n) equal to two and three, respectively, which are closer to E_F . These states contribute strongly to the majority-spin FE current. The minority-spin QW states are shown in Fig. 2(e). For the two ML Fe films, the minority-spin QW state with Δ_1 symmetry and $n = 1$ (labeled as 2_{\min}) is at E_F , while the majority-spin FE current comes mainly from the W substrates near E_F (a representative state is labeled as 2_{maj}). The minority-spin

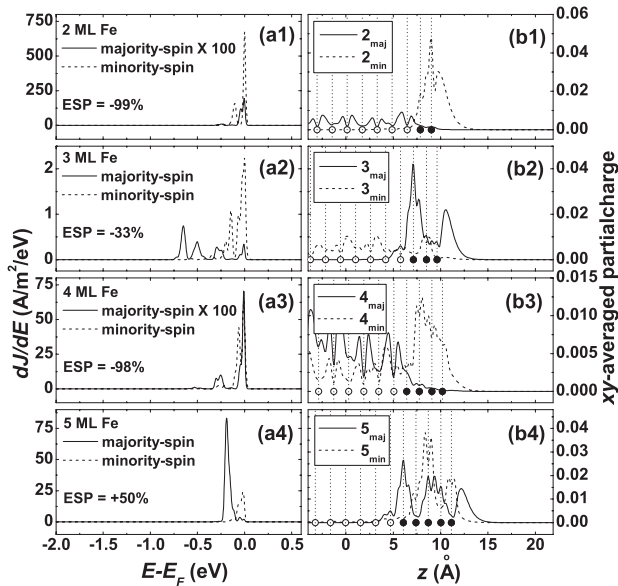


FIG. 1. Panels (a1) through (a4) show the TED curves of the spin-polarized FE currents from Fe/W(001) under $E = 0.2$ V/Å, and panels (b1) through (b4) show the xy -averaged partial charge distributions of representative states contributing to most of the FE current (solid line: majority-spin; dashed line: minority-spin). The vertical dot lines indicate the atomic positions in the z direction. The solid and open circles mark the Fe and W atom positions.

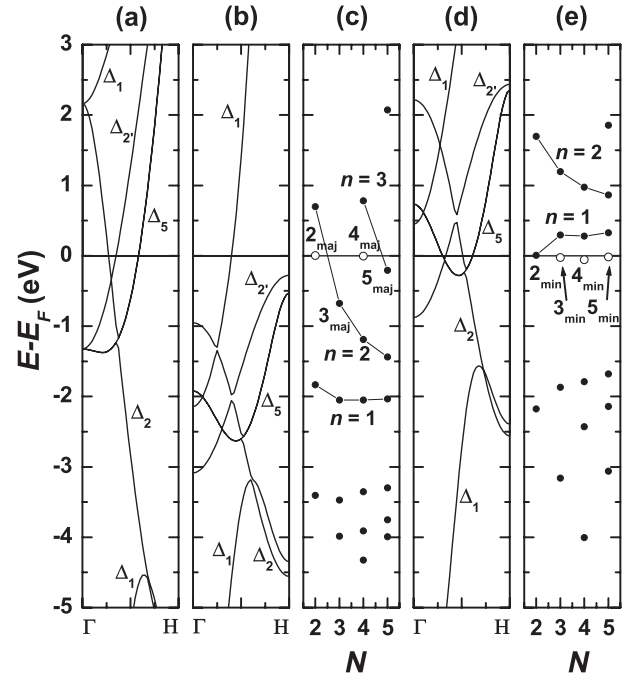


FIG. 2. Bulk energy bands along ΓH for bcc W [panel (a)], majority-spin bct Fe [panel (b)] and minority-spin bct Fe [panel (d)]. Panels (c) and (e) show, respectively, majority- and minority-spin QW states (solid dots) at $\bar{\Gamma}$ with Δ_1 symmetry for N layers Fe on W(001), and the energies of other non-QW states (open circles) contributing to most of the current are also shown.

QW state completely dominates the FE current for two reasons. First, the QW state extends further from the surface than the W substrate state, as can be seen from the (pseudo) charge density along the z -direction in Fig. 1, panel (b1). Numerically, we found that the $|f_{\sigma,n}(\vec{k}_{\parallel} + \vec{G}_{\parallel}, z_m)|^2$ factor (see Eq. (1)) is much larger for minority-spin 2_{\min} state than the 2_{maj} state, and a large $|f_{\sigma,n}(\vec{k}_{\parallel} + \vec{G}_{\parallel}, z_m)|^2$ factor gives a large FE current. Second, 2_{\min} is of Δ_1 symmetry, but the band corresponding to the majority-spin state does not have Δ_1 symmetry at $\bar{\Gamma}$.

The minority-spin QW state plays a key role only at two ML. For thicker Fe films, all minority-spin QW states at $\bar{\Gamma}$ point with Δ_1 symmetry are far from the E_F , as shown in Fig. 2(e). For the three ML Fe film, the representative state, 3_{\min} , which contributes most of the minority-spin current, is off Brillouin zone center and of the extended nature (see Fig. 1, panel (b2)), while the QW state, 3_{maj} , is at $\bar{\Gamma}$ and of Δ_1 symmetry. These results might suggest that FE should be mostly majority-spin. However, the contrary is found to be true. The FE is again dominated by the minority-spin current, and this is because the 3_{maj} state is at about 0.68 eV below the E_F , while the 3_{\min} state is at E_F . Thus 3_{maj} have a larger tunneling barrier that inhibits the FE current. When the Fe film becomes thicker, surface resonance states begin to form. At four ML, the majority-spin current is dominated by states near E_F that extend into the W bulk [of which a representative state, 4_{maj} , is shown in Fig. 1, panel (b3)], but the minority-spin has a surface resonance state 4_{\min} mainly localized in the Fe layers just near E_F [see Fig. 1, panel (b3)]. This surface resonance state dominates

the minority-spin current. The surface resonance state extends much further out of the emitter surface than does the extended state 4_{maj} , so the FE current from the four ML Fe/W(001) is strongly minority-spin dominant. For the five ML Fe film, the QW state 5_{maj} at the $\bar{\Gamma}$ point and of Δ_1 symmetry competes with a surface state, 5_{\min} , contributing to most of the minority-spin current. In Fig. 1, panel (b4), the partial charge distributions suggest that though these two states are localized in the Fe layers, the 5_{maj} state extends further out of the emitter surface than the 5_{\min} state. This leads to a majority-spin-polarized FE current from the five ML Fe film [see Fig. 1, panel (a4)], even though the LDOS at E_F is still predominately minority-spin.

The effect of the external E -field strength on the spin-polarization of the FE current is shown in Fig. 3. We see that the high minority-spin-polarizations of the FE currents from the two and four ML Fe films are robust up to $F = 0.30$ V/Å. On the other hand, the ESP values for the three and five ML Fe films are field dependent. This interesting thickness dependence can be understood qualitatively as follows. According to Fowler-Nordheim (F-N) theory [20,21], the FE current density from a metal surface is $J \propto F^2 \exp\{-[4\sqrt{2m}/(3\hbar e)]\phi^{1.5}/F\}$, where ϕ is the work function. If the FE current comes mainly from states with energy ε_M , the work function ϕ should be operationally replaced by an “effective” work function, $\phi_{\text{eff}} \approx \phi + E_F - \varepsilon_M$ [11]. The F-N plot for the material with a higher ‘effective’ work function has a larger slope, and thus the current increases more rapidly when the E -field is enhanced. For the three ML Fe film, the majority-spin FE current, $J_{\text{total},\uparrow}$, has a larger slope in the F-N plot than does

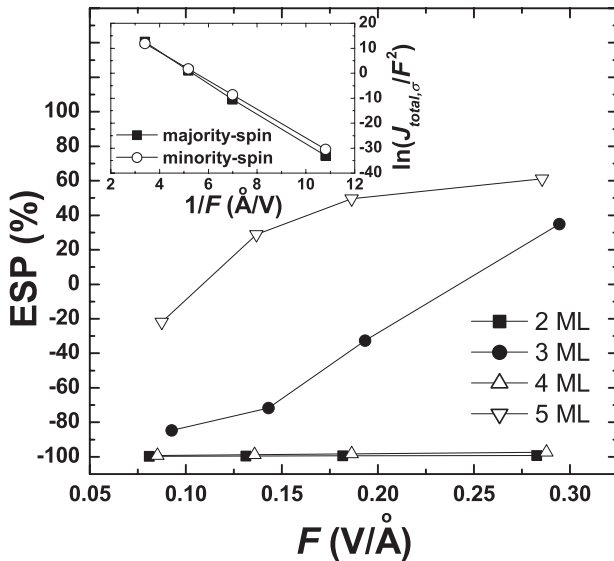


FIG. 3. The ESP of the FE currents from Fe/W(001) under different E -field strengths. Inset: the F-N plots of the majority- and minority-spin FE currents (unit: A/m²) from the three ML Fe/W(001).

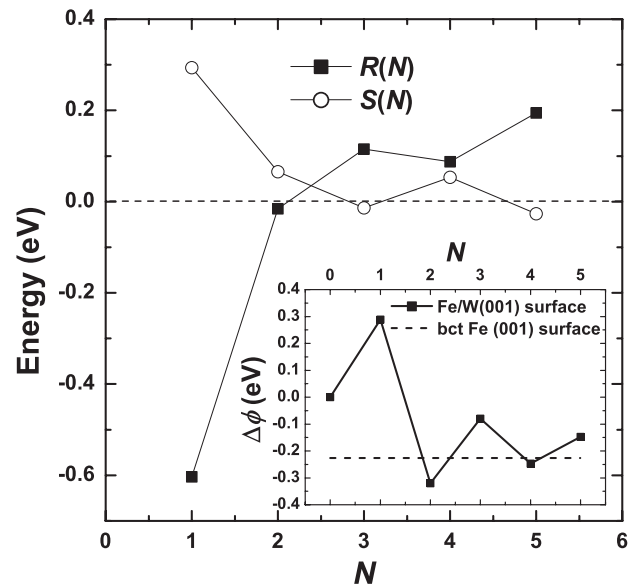


FIG. 4. The functions, R and S (see text) plotted as the functions of the Fe film thickness N . Inset: the work functions of the Fe/W(001) using the work function of W(001) as a reference.

the minority-spin FE current, $J_{\text{total},\downarrow}$, because the 3_{maj} state is 0.68 eV lower than the 3_{min} state. The $J_{\text{total},\uparrow}$ can exceed the $J_{\text{total},\downarrow}$ when the E -field is larger than a threshold, as shown by the inset in Fig. 3. In the case of the five ML Fe film, there is also an energy difference (~ 0.20 eV) between the 5_{maj} and 5_{min} states.

A good field emitter should be stable and have a low work function. Figure 4 shows the plots of two functions related to the stability of the Fe coating: $R(N) = E(N) - E(N - 1)$, and $S(N) = [E(N + 1) + E(N - 1)]/2 - E(N)$, where $E(N)$ is the surface energy per surface atom for N ML Fe films on W(001). One can see that both $R(1)$ and $R(2)$ are negative, and $R(N)$ turns positive when $N \geq 3$. This means that one and two ML Fe films are thermodynamically stable relative to three-dimensional (3D) bulk Fe islands on W(001) and one ML of Fe on W(001), respectively. This is consistent with the experimental observation that two ML Fe wetting layers are stable upon annealing on W(001) [6–9], followed by 3D growth for higher coverages beyond 600 K [8,9,22]. The value of $S(4)$ is found to be positive, which suggests that the four ML is metastable (more stable than three and five ML films), consistent with a recent experimental observation [10]. The inset in Fig. 4 gives $\Delta\phi = \phi_{\text{Fe/W}(001)} - \phi_{\text{W}(001)}$, which is the work function of these Fe/W(001) surfaces using W(001) as a reference. The work function approaches $\phi_{\text{Fe}(001)'}$ in an oscillatory manner, where $\phi_{\text{Fe}(001)'}$ is the work function of a bct Fe(001) surface with the in-plane lattice constants matching those of the W(001) and the z -coordinates relaxed. We note, in particular, that the two and four ML Fe covered surfaces have low work functions and thus are favorable to field emissions.

In summary, we studied the spin-polarized FE from the Fe pseudomorphical films on W(001) and identified some configurations that can give strongly spin-polarized FE, and these configurations have the additional advantage of being stable with low work functions. The thickness-dependent FE properties are traced to spin-polarized QW and surface resonance states localized in the Fe layers.

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